QDLASER QLD156N-5050

1550 nm 50mW DFB Laser Butterfly Package

Preliminary

C00177-01 October 2015



1. DESCRIPTION

The QLD156N-5050 is a 1550-nm distributed feedback (DFB) laser for use in seeder for fiber lasers, sensing applications and telecom/data communications. The laser is assembled into a 14-pin butterfly package with an optical isolator, a monitor PD and a thermo-electric cooler.

2. FEATURES

- 50-mW fiber output power
- Single longitudinal mode operation at 1550 nm
- Fiber-pigtailed 14-pin butterfly package with a TEC

3. APPLICATION

- Seeder for fiber lasers
- Sensing
- Telecom/data communication

4. ABSOLUTE MAXIMUM RATING

		$(T_C = 25^{\circ}C, unless c$	otherwise specified)
PARAMETER	SYMBOL	RATING	UNIT
LD Forward Current (CW)	I_F	500	mA
LD Reverse Voltage	V _{RLD}	2	V
PD Forward Current	IV _{FPD}	10	mA
PD Reverse Voltage	V _{RPD}	20	V
TEC Drive Current	I _{TEC}	2	A
TEC Drive Voltage	V _{TEC}	4.3	V
Operation Temperature	T _c	-20 to 70	°C
Storage Temperature	T _{stg}	-40 to 85	°C
Lead Soldering Temperature (10 s)	T _{sld}	260	°C

QDLASER

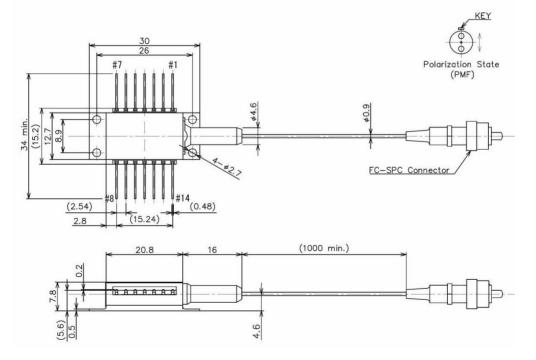
QLD156N-5050

C00177-01

5. OPTICAL AND ELECTRICAL CHARACTERISTICS

5. OI IICAL AND ELECTR		10121051105	$(T_{LD} = 2)$	25°C, unle	ss otherwis	e specified)
PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Peak Wavelength	λ_p	CW, $P_f = 50 \text{ mW}$	1547	1550	1553	nm
Spectral Width (FWHM)	Δν	CW, $P_f = 50 \text{ mW}$	-	2	5	MHz
Temperature Coefficient of λ_p	$d\lambda_p/dT$	CW	-	0.1	-	nm/K
Current Coefficient of λ_p	$d\lambda_p/dI$	CW	-	0.01	-	nm/mA
Threshold Current	I _{th}	CW	-	-	40	mA
CW Fiber Output Power	\mathbf{P}_{f}	CW, I _f =300 mA	50	-	-	mW
Operation Current	I _{op}	CW, $P_f = 50 \text{ mW}$	-	-	300	mA
Operation Voltage	V_{op}	CW, $P_f = 50 \text{ mW}$	-	-	2.5	V
Sidemode Suppression Ratio	SMSR	CW, P _f =50 mW	35	-	-	dB
Polarization Extinction Ratio	PER	CW	20	-	-	dB
Monitor PD Current	Im	CW, P _f =50 mW, Vr=5V	100	-	2000	μΑ
Thermistor Resistance	R _{th}	$T_{LD} = 25^{\circ}C,$ B=3900+/-100K	9.5	10	10.5	kΩ
TEC Drive Current	I _{TEC}	P_{f} =50 mW, T_{C} = 70°C,	-	-	1.2	А
TEC Drive Voltage	V _{TEC}	$P_{f}=50 \text{ mW}, T_{C}=70^{\circ}C$	-	-	2.5	V

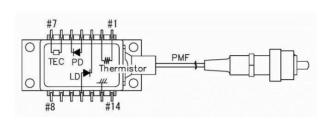
6. OUTLINE DRAWING





7. PIN CONFIGURATION

No.	Description	No.	Description
1	Thermistor	8	NC
2	Thermistor	9	NC
3	Laser Cathode	10	NC
4	PD Anode	11	Laser Anode
5	PD Cathode	12	NC
6	TEC (+)	13	Case Ground
7	TEC (-)	14	NC



8. NOTICE

• Safety Information

This product is classified as Class 3B laser product, and complies with 21 CFR Part 1040.10. Please do not take a look at laser lighting in operations since laser devices may cause troubles to human eyes. Please do not eat, burn, break and make chemical process of the products since they contain GaAs material.

• Handling products

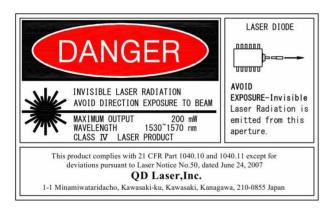
Semiconductor lasers are easily damaged by external stress such as excess temperature and ESD.

Please pay attention to handling products, and use within range of maximum ratings.

QD Laser takes no responsibility for any failure or unusual operation resulting from improper handling, or unusual physical or electrical stress.

• RoHS

This product conforms to RoHS compliance related EU Directive 2011/65/EU.



QD Laser, Inc.

Contact : info@qdlaser.com http://www.qdlaser.com

Copyright 2015 All Rights Reserved by QD Laser, Inc.

Keihin Bldg. 1F 1-1 Minamiwatarida-cho, Kawasaki-ku, Kawasaki, Kanagawa Zip 210-0855 Japan

All company or product names mentioned herein are trademarks or registered trademarks of their respective owners. Information provided in this data sheet is accurate at time of publication and is subject to change without advance notice.